

Product Fact Sheet

**Industrial** SD/SDHC Memory Card





## S-450 SERIES (UHS-I, SLC)

## INDUSTRIAL SD/SDHC MEMORY CARD - 512MBYTE TO 32GBYTE

## Main Feature

- Fully compliant with SD Memory Card specification 3.0
  - SD ultra high speed mode, speed class 1 (SDR104)
  - SD high speed mode, up to speed class 10
  - SD2.0 SDHC backward compliant, default speed and high speed mode
  - o FAT32 up to 32GB SDHC
- High performance 3.0 specification
  - o SD burst up to 104MB/s
  - SD Normal speed o...25MHz clock rate
  - o SD High speed 25...50MHz clock rate
  - o SD UHS-I speed o...50MHz (DDR) and o...208MHz (SDR)
  - o Up to 90MByte/sec sequential data rate
- Power Supply: (Low-power CMOS technology)
  - o 2.7...3.6V operating voltage
- Standard SD Memory card form factor
  - o 32.0mm x 24.0mm x 2.1mm and Write Protect slider
- Optimized FW algorithms especially for high read access and long data retention applications
  - Patented power-off reliability technology
  - Wear Leveling technology
    - Equal wear leveling of static and dynamic data. The wear leveling assures that dynamic data as well as static data is balanced evenly across the memory. With that the maximum write endurance of the device is guaranteed
  - Write Endurance technology
    - Due to intelligent wear leveling an even use of the entire flash is guaranteed, regardless how much "static" (0S) data is stored.
  - o Read Disturb Management
    - The read commands are monitored and the content is refreshed when critical levels have occurred
  - Data Care Management
    - The interruptible background process maintain the user data for Read Disturb effects or Retention degradation due to high temperature effects
  - o Near Miss ECC technology
    - Minimize the risk of uncorrectable bit failure over the product life time. Each read command analyzes the ECC margin level and refresh data if necessary
  - Diagnostic features with Life Time Monitoring tool support
- High reliability
  - o SLC Flash
  - Designed for industrial market especially read intensive application like navigation, infotainment, POS/POI, medical and general boot medium use case
  - The product is optimized for long life cycle that requires good data retention because of high temperature mission profile.
  - For less write and performance critical applications S-4x the more cost efficient S-4x series MLC cards could be used
  - Number of card insertions/removals 20,000
  - o Extended and Industrial Temperature range -25° up to 85°C and -40° up to 85°C
  - o SIP (System In Package) process for extreme dust, water and ESD proof
  - Selected AEC-Q100 qualification
- Controlled BOM & PCN process
- Manufactured in a TS 16949 certified factory
- Customized options like CID registers, CPRM keys, firmware incl. settings and marking by projects

















Switzerland





Order Information for S-450 Series UHS-I SD Memory Cards

Density	Part Number	Temp. Range	Flash Technology
512MB	SFSD0512LgBM1TO-t-ME-2xx-STD		
1GB	SFSD1024LgBM1TO-t-DF-2xx-STD		
2GB	SFSD2048LgBM1TO-t-QG-2xx-STD	t - E 2500 to 0500	
4GB	SFSD4096LgBM1TO-t-ME-2xx-STD	t = E -25°C to 85°C t = I -40°C to 85°C	SLC NAND Flash
8GB	SFSD8192LgBM1TO-t-DF-2xx-STD	1 - 1 - 40 °C 10 85 °C	
16GB	SFSD016GLgBM1TO-t-QG-2xx-STD		
32GB	SFSD032GLgBM1TO-t-NG-2xx-STD		

g = generation; x = options, firmware and custom configuration

**System Performance** 

System Performance	typ	max	Unit
Burst Data transfer Rate (max clock 208MHz SDR)		104	
Sustained Sequential Read 512MB / 1GB2GB / 4GB32GB	28 / 28 / 88	30 / 34 / 90	MB/s
Sustained Sequential Write 512MB / 1GB2GB / 4GB / 8GB32GB	18 / 20 / 37 / 73	20   24   40   75	

Current Consumption @3.3V	typ	max	Unit	
Write	60	120		
Read	70	120	m 1	
Autoread	120	130	mΑ	
Idle	1.2	5		

**Physical Dimensions** 

Physical Dimensions	Value	Unit
Length	32.00±0.10	
Width	24.00±0.10	mm
Thickness	2.10±0.15	
Weight (typ.)	2	g

**Recommended Temperature Conditions** 

Parameter	min	typ	max	Unit
Extended Operating Temperature	-25	25	85*)	°C
Industrial Operating Temperature	-40	25	85*)	٥(
Storage Temperature	-40	25	100*)	٥٢

<sup>\*)</sup> high temperature storage without operation reduces the data retention, in operation the data will be refreshed, if data error issues were detected

**Humidity and EMC** 

Parameter	Operating	Non Operating	
Humidity (non-condensing)	max 95%		
ESD	Non Contact Pads area: ±15 kV (air discharge), according to IEC61000-4-2	Contact Pads:  ±6 kV, according to IEC61000-4-2  Non Contact Pads area:  ±8kV (indirect) contact discharge, according to IEC61000-4-2	

**Durability** 

Parameter	Operating	Non Operating	
Salt water spray	3% NaCl/35°C; 24h acc. MIL STD Method 1009		
Insertions / Drop test	>20,000 / 1.5m free fall		
Bending / Torque / Bump	10N / 0.15Nm or ±2.5deg		
Shock / Vibration (peak -to-peak)	1500G max / 50G max		
Data Retention initial @ 40°C	10 years		

For more information on SD Memory card Specification, please visit SD association (www.sdcard.org)

## Why Swissbit?

Swissbit strives to create innovative technologies for future market opportunities utilizing a highly skilled inhouse product research and development team. Swissbit maintains a marketing edge by continuing to manufacture world-class high quality memory products and providing customers with both high value and low cost of ownership achieved through efficient processes and procedures.